JOS FET

Small switching (60V, 2A) 25K2094

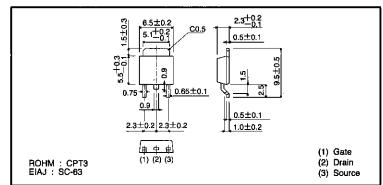
Features

- 1) Low on-resistance.
- 2) High-speed switching.
- 3) Wide SOA (safe operating area).
- 4) Low-voltage drive (4V).
- 5) Easily designed drive circuits.
- 6) Easy to use in parallel.

Structure

Silicon N-channel MOSFET transistor

●External dimensions (Unit: mm)



■Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		Voss	60	V
Gate-source voltage		Vgss	±20	٧
Drain current	Continuous	lo	2	Α
	Pulsed	DP*	8	Α
Drain reverse current	Continuous	lpa	2	Α
	Pulsed	DRP*	8	Α
Total power dissipation(Tc=25°C)		Рь	20	w
Channel temperature		Tch	150	°C
Storage temperature		Tstg	-55~150	°C

^{*} Pw≦300 μs, Duty cycle≦2%

Packaging specifications

Туре	Package name	Bulk
	Code	TL
	Basic ordering unit (pieces)	2500
2SK2094		0

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate leakage current	lass	_	_	±100	nA	V _{DS} =±20V, V _{DS} =0V
Drain-source breakdown voltage	V(BR)DSS	60		_		Ib=1mA, Vgs=0V
Drain cutoff current	loss			100	μΑ	V _{DS} =60V, V _{GS} =0V
Gate threshold voltage	VGS(th)	1		2.5	٧	V _{DS} =10V, I _D =1mA
Drain course on state resistance	RDS(on)	_	0.3	0.35	Ω	ID=1A, VGS=10V
Drain-source on-state resistance			0.4	0.5		ID=1A, VGS=4V
Forward transfer admittance	Yts	1	_	_	S	V _{DS} =10V, I _D =1A
Input capacitance	Ciss	_	400		рF	V _{DS} =10V
Output capacitance	Coss	_	150		рF	V _{GS} =0V
Reverse transfer capacitance	Crss	_	50	-	рF	f=1MHz
Turn-on delay time	td(on)	_	10	_	ns	lo=1A, Voo≒30V
Rise time	tr	_	20	—	ns	V _{GS} =10V
Turn-off delay time	td(off)	-	100	_	ns	RL=30 Ω
Fall time	tr	_	40	_	ns	Re=10Ω
Reverse recovery time	trr		100	_	ns	IDR=2A, Vgs=0V, di/dt=50A/ μs

Electrical characteristic curves

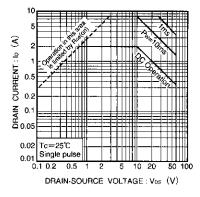


Fig.1 Maximum Safe Operating Area

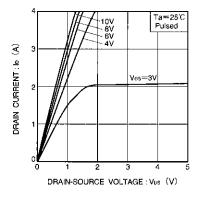


Fig.2 Typical Output Characteristics

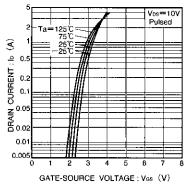


Fig.3 Typical Transfer Characteristics

IOS FE

Electrical characteristic curves

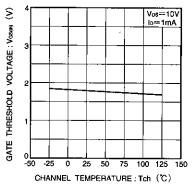


Fig.4 Gate Threshold Voltage vs. Channel Temperature

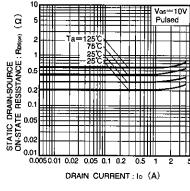


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current (I)

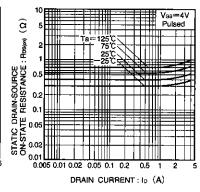


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current (II)

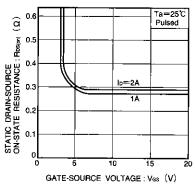


Fig.7 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

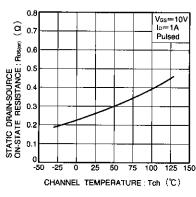


Fig.8 Static Drain-Source On-State Resistance vs. Channel Temperature

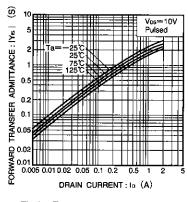


Fig.9 Forward Transfer Admittance vs. Drain Current

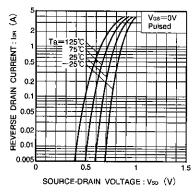


Fig.10 Reverse Drain Current vs. Source-Drain Voltage (I)

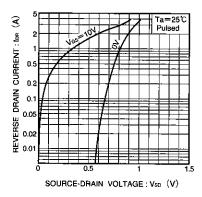


Fig.11 Reverse Drain Current vs. Source-Drain Voltage (I)

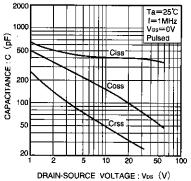
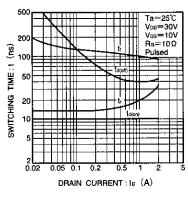


Fig.12 Typical Capacitance vs. Drain-Source Voltage

Electrical characteristic curves



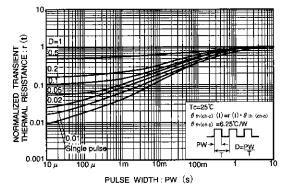
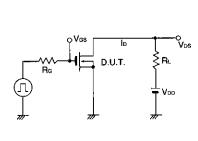


Fig.13 Switching Characteristics (See Figure. 15 and 16 for measurement circuits)

Fig.14 Normalized Transient Thermal Resistance vs. Pulse Width

Switching characteristics measurement circuit



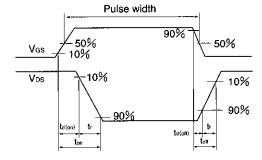


Fig.15 Switching Time Measurement Circuit

Fig.16 Switching Time Waveforms

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